

10A Avg.

600 Volts

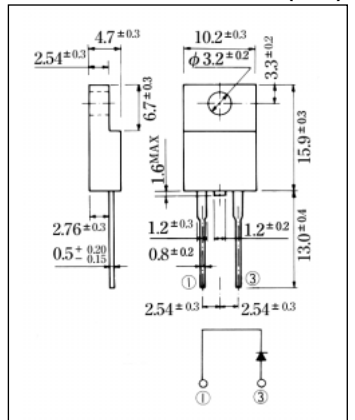
FRED

FSU10U60

最大定格 Maximum Ratings

Item	Symbol	Conditions	Unit
くり返しピーク逆電圧 Repetitive Peak Reverse Voltage	V_{RRM}	600	V
平均整流電流 Average Rectified Forward Current	I_O	50Hz、正弦半波、抵抗負荷 50Hz Half Sine Wave, Resistance Load	$T_c=60^\circ\text{C}$ 10 A
実効順電流 R.M.S. Forward Current	$I_F(\text{RMS})$	15.7	A
サージ順電流 Surge Forward Current	I_{FSM}	110 50Hz正弦半波、1サイクル、非くり返し 50Hz Half Sine Wave, 1cycle, Non-repetitive	A
動作接合温度範囲 Operating Junction Temperature Range	T_{jw}	-40~+150	$^\circ\text{C}$
保存温度範囲 Storage Temperature Range	T_{stg}	-40~+150	$^\circ\text{C}$
締付トルク Mounting torque	F_{tor}	推奨値 Recommended Value	0.5 N·m

OUTLINE DRAWING(mm)



APPROX. NET WEIGHT:2.1 g

電氣的・熱的特性 Electrical/Thermal Characteristics

Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
ピーク逆電流 Peak Reverse Current	I_{RM}	$T_j=25^\circ\text{C}$, $V_{RM}=V_{RRM}$, 一素子あたり Per Diode	—	—	30	μA
ピーク順電圧 Peak Forward Voltage	V_{FM}	$T_j=25^\circ\text{C}$, $I_{FM}=10\text{A}$, 一素子あたり Per Diode	—	1.9	2.3	V
逆回復時間 Reverse Recovery Time	t_{rr}	$I_{FM}=10\text{A}$, $-di/dt=50\text{A}/\mu\text{s}$, $T_j=25^\circ\text{C}$	—	30	45	ns
熱抵抗 Thermal Resistance	$R_{th(j-c)}$	接合部・ケース間 Junction to Case	—	—	4	$^\circ\text{C}/\text{W}$
	$R_{th(c-f)}$	ケース・フィン間 Case to Fin	—	—	1.5	$^\circ\text{C}/\text{W}$

定格・特性曲線

FIG.1

順電圧特性
FORWARD CURRENT VS. VOLTAGE

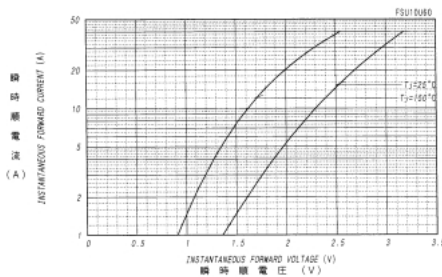


FIG.2

平均順電圧損失特性
AVERAGE FORWARD POWER DISSIPATION

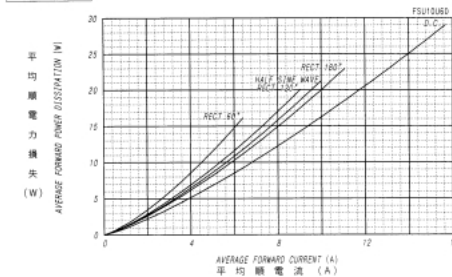


FIG.3

平均順電流-ケース温度定格
AVERAGE FORWARD CURRENT VS. CASE TEMPERATURE

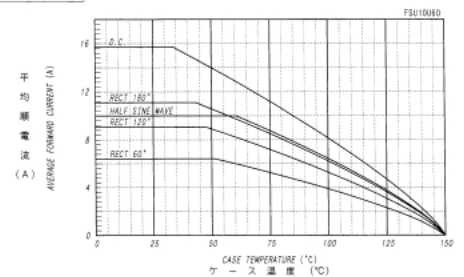


FIG.4

サージ順電流定格
SURGE CURRENT RATINGS

f=50Hz, Sine Wave, Non-Repetitive, No Load

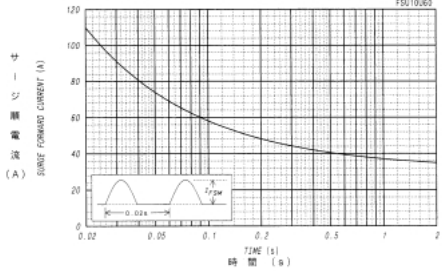


FIG.5

サージ実効順電流定格
SURGE RMS CURRENT RATINGS

